

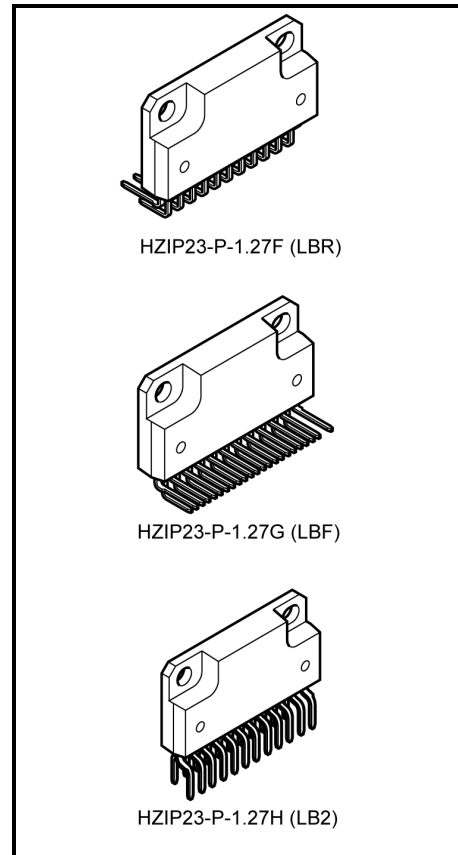
TPD4105AK

The TPD4105AK is a DC brushless motor driver using high-voltage PWM control. It is fabricated using a high-voltage SOI process. The device contains a level shift high side driver, low side driver, IGBT outputs, FRDs and protective functions for under-voltage protection circuits, and a thermal shutdown circuit. It is easy to control a DC brush less motor by just putting logic inputs from a MPU or motor controller to the TPD4105AK.

Features

- Bootstrap circuits give simple high-side supply.
- Bootstrap diodes are built in.
- A dead time can be set as a minimum of 1.4 μ s and it is the best for a Sine-wave from drive.
- 3-phase bridge output using IGBTs.
- FRDs are built in.
- Included under-voltage protection, and thermal shutdown.
- The regulator of 7V (typ.) is built in.
- Package: 23-pin HZIP.

This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge.



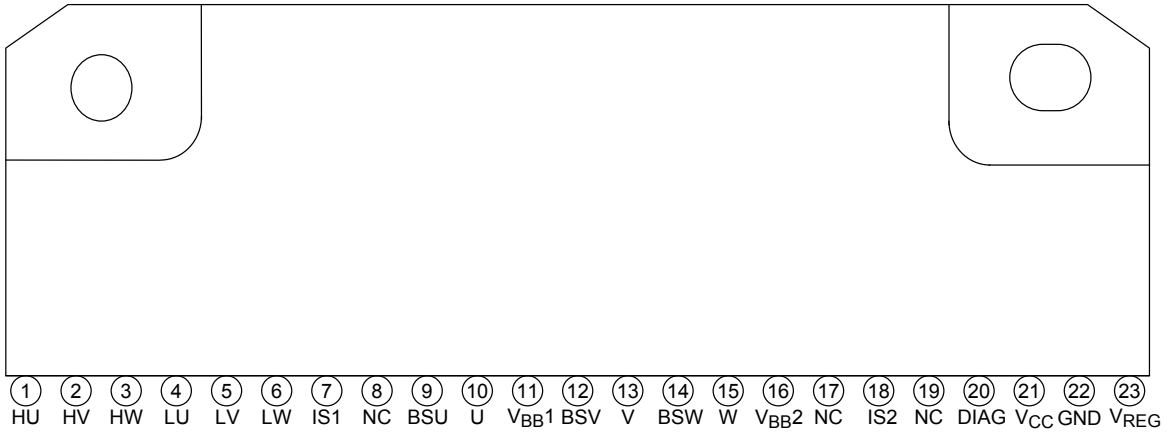
Weight

HZIP23-P-1.27F : 6.1 g (typ.)

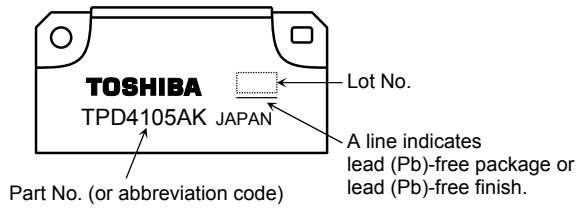
HZIP23-P-1.27G : 6.1 g (typ.)

HZIP23-P-1.27H : 6.1 g (typ.)

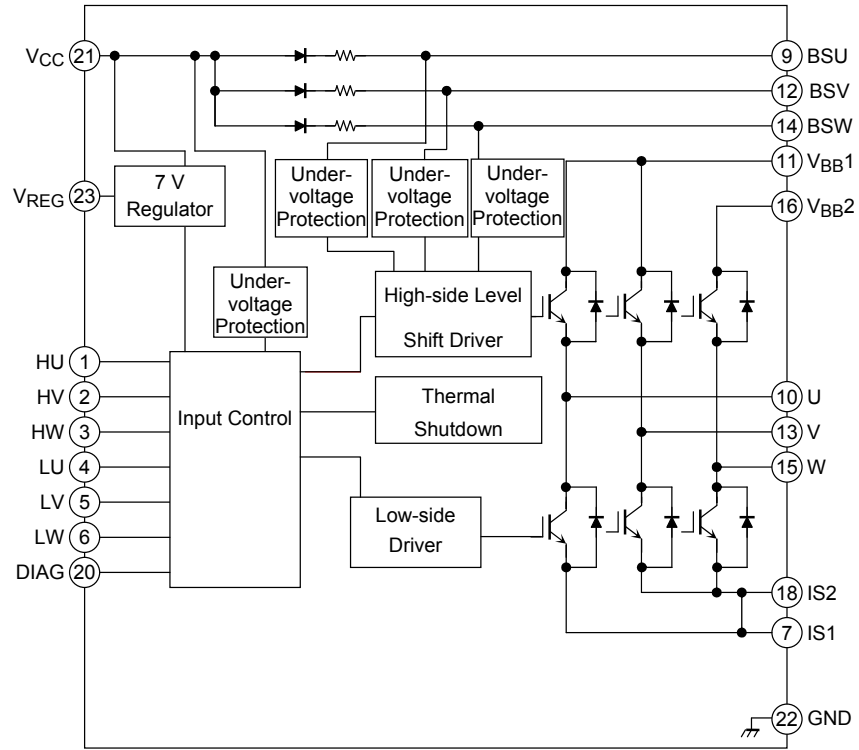
Pin Assignment



Marking



Block Diagram

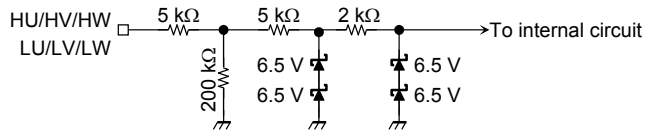


Pin Description

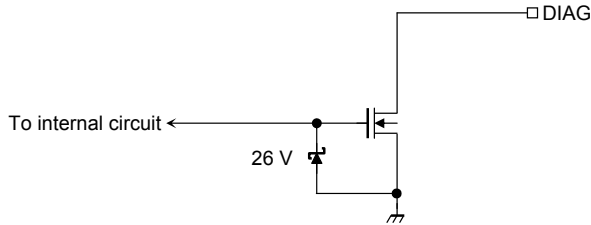
Pin No.	Symbol	Pin Description
1	HU	The control terminal of IGBT by the side of U top arm. It turns off less than 1.5V. It turns on more than 3.5V.
2	HV	The control terminal of IGBT by the side of V top arm. It turns off less than 1.5V. It turns on more than 3.5V.
3	HW	The control terminal of IGBT by the side of W top arm. It turns off less than 1.5V. It turns on more than 3.5V.
4	LU	The control terminal of IGBT by the side of U bottom arm. It turns off less than 1.5V. It turns on more than 3.5V.
5	LV	The control terminal of IGBT by the side of V bottom arm. It turns off less than 1.5V. It turns on more than 3.5V.
6	LW	The control terminal of IGBT by the side of W bottom arm. It turns off less than 1.5V. It turns on more than 3.5V.
7	IS1	IGBT emitter and FRD anode pin.
8	NC	Unused pin, which is not connected to the chip internally.
9	BSU	U-phase bootstrap capacitor connecting pin.
10	U	U-phase output pin.
11	V _{BB1}	U and V-phase high-voltage power supply input pin.
12	BSV	V-phase bootstrap capacitor connecting pin.
13	V	V-phase output pin.
14	BSW	W-phase bootstrap capacitor connecting pin.
15	W	W-phase output pin.
16	V _{BB2}	W-phase high-voltage power supply input pin.
17	NC	Unused pin, which is not connected to the chip internally.
18	IS2	IGBT emitter and FRD anode pin.
19	NC	Unused pin, which is not connected to the chip internally.
20	DIAG	With the diagnostic output terminal of open drain, a pull-up is carried out by resistance. It turns on at the time of unusual.
21	V _{CC}	Control power supply pin.(15V typ.)
22	GND	Ground pin.
23	V _{REG}	7V regulator output pin.

Equivalent Circuit of Input Pins

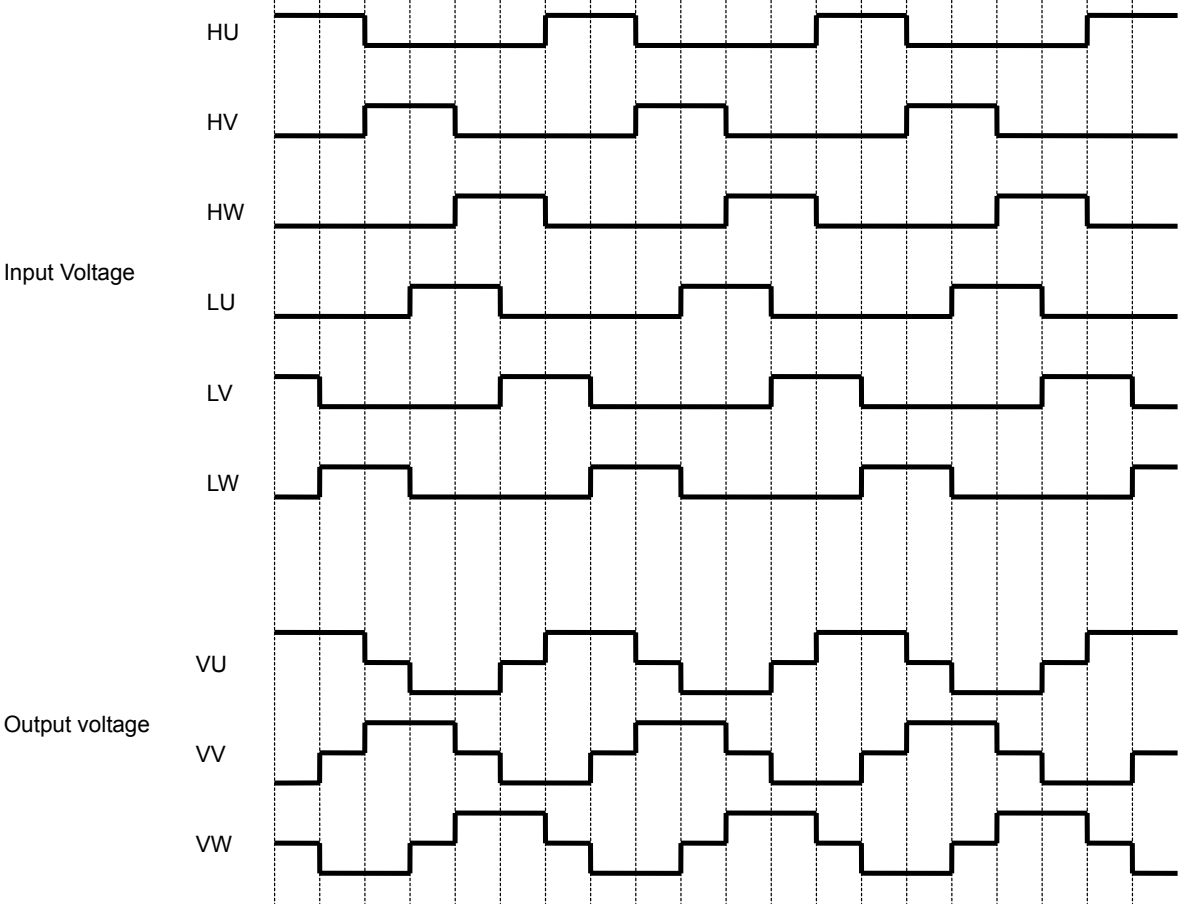
Internal circuit diagram of HU, HV, HW, LU, LV, LW input pins



Internal circuit diagram of DIAG pin



Timing Chart



Truth Table

Mode	Input						Top arm			Bottom arm			DIAG
	HU	HV	HW	LU	LV	LW	U phase	V phase	W phase	U phase	V phase	W phase	
Normal	H	L	L	L	H	L	ON	OFF	OFF	OFF	ON	OFF	OFF
	H	L	L	L	L	H	ON	OFF	OFF	OFF	OFF	ON	OFF
	L	H	L	L	L	H	OFF	ON	OFF	OFF	OFF	ON	OFF
	L	H	L	H	L	L	OFF	ON	OFF	ON	OFF	OFF	OFF
	L	L	H	H	L	L	OFF	OFF	ON	ON	OFF	OFF	OFF
	L	L	H	L	H	L	OFF	OFF	ON	OFF	ON	OFF	OFF
Thermal shutdown	H	L	L	L	H	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
	H	L	L	L	L	H	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	H	L	L	L	H	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	H	L	H	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	L	H	H	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	L	H	L	H	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
Under-voltage	H	L	L	L	H	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
	H	L	L	L	L	H	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	H	L	L	L	H	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	H	L	H	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	L	H	H	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ON
	L	L	H	L	H	L	OFF	OFF	OFF	OFF	OFF	OFF	ON

Notes: Release of thermal shutdown protection and under voltage protection depends release of a self-reset.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{BB}	500	V
	V _{CC}	18	V
Output current (DC)	I _{out}	3	A
Output current (pulse)	I _{out}	4	A
Input voltage	V _{IN}	-0.5~7	V
V _{REG} current	I _{REG}	50	mA
DIAG current	I _{DIAG}	20	mA
Power dissipation (Ta = 25°C)	P _C	4	W
Power dissipation (Tc = 25°C)	P _C	20	W
Operating temperature	T _{jopr}	-20~135	°C
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55~150	°C
Lead-heat sink isolation voltage	V _{hs}	1000 (1 min)	V _{rms}

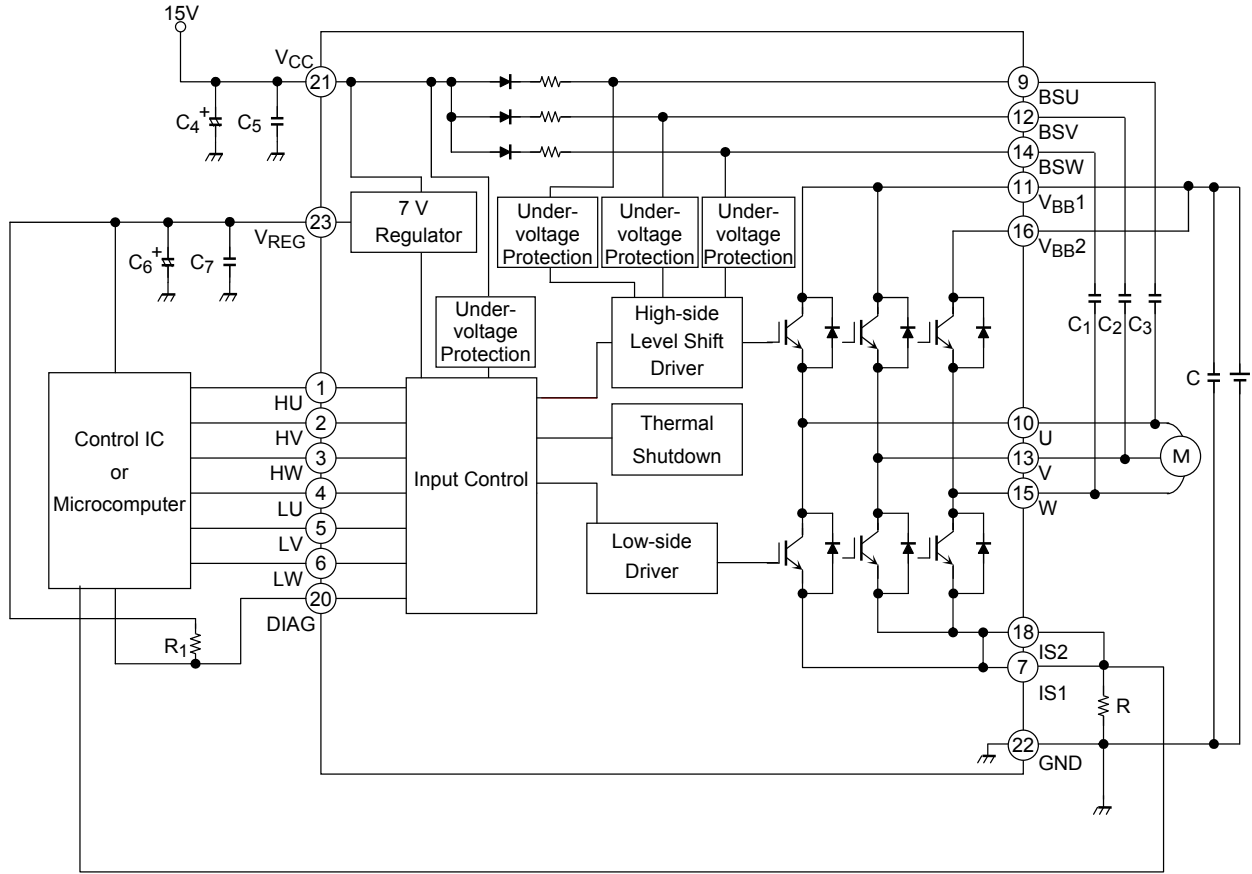
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Operating power supply voltage	V_{BB}	—	50	280	450	V
	V_{CC}	—	13.5	15	16.5	
Current dissipation	I_{BB}	$V_{BB} = 450\text{ V}$	—	—	0.5	mA
	I_{CC}	$V_{CC} = 15\text{ V}$	—	0.8	5	
	$I_{BS (ON)}$	$V_{BS} = 15\text{ V}$, high side ON	—	230	410	μA
	$I_{BS (OFF)}$	$V_{BS} = 15\text{ V}$, high side OFF	—	200	370	
Input voltage	V_{IH}	$V_{IN} = \text{“H”}$	3.5	—	—	V
	V_{IL}	$V_{IN} = \text{“L”}$	—	—	1.5	
Input current	I_{IH}	$V_{IN} = 5\text{ V}$	—	—	150	μA
	I_{IL}	$V_{IN} = 0\text{ V}$	—	—	100	
Output saturation voltage	V_{CEsatH}	$V_{CC} = 15\text{ V}$, $I_C = 1.5\text{ A}$, high side	—	2.3	3	V
	V_{CEsatL}	$V_{CC} = 15\text{ V}$, $I_C = 1.5\text{ A}$, low side	—	2.3	3	
FRD forward voltage	V_{FH}	$I_F = 1.5\text{ A}$, high side	—	1.6	2.0	V
	V_{FL}	$I_F = 1.5\text{ A}$, low side	—	1.6	2.0	
BSD forward voltage	$V_F (BSD)$	$I_F = 500\mu\text{A}$	—	0.8	1.2	V
Regulator voltage	V_{REG}	$V_{CC} = 15\text{ V}$, $I_O = 30\text{ mA}$	6.5	7	7.5	V
Thermal shutdown temperature	TSD	$V_{CC} = 15\text{ V}$	135	—	185	$^{\circ}\text{C}$
Thermal shutdown hysteresis	ΔTSD	$V_{CC} = 15\text{ V}$	—	50	—	$^{\circ}\text{C}$
V_{CC} under-voltage protection	V_{CCUVD}	—	10	11	12	V
V_{CC} under-voltage protection recovery	V_{CCUVR}	—	10.5	11.5	12.5	V
V_{BS} under-voltage protection	V_{BSUVD}	—	8	9	9.5	V
V_{BS} under-voltage protection recovery	V_{BSUVR}	—	8.5	9.5	10.5	V
DIAG saturation voltage	$V_{DIAGsat}$	$I_{DIAG} = 5\text{ mA}$	—	—	0.5	V
Output-on delay time	t_{on}	$V_{BB} = 280\text{ V}$, $V_{CC} = 15\text{ V}$, $I_C = 1.5\text{ A}$	—	1.2	3	μs
Output-off delay time	t_{off}	$V_{BB} = 280\text{ V}$, $V_{CC} = 15\text{ V}$, $I_C = 1.5\text{ A}$	—	1.0	3	μs
Dead time	t_{dead}	$V_{BB} = 280\text{ V}$, $V_{CC} = 15\text{ V}$, $I_C = 1.5\text{ A}$	1.4	—	—	μs
FRD reverse recovery time	t_{rr}	$V_{BB} = 280\text{ V}$, $V_{CC} = 15\text{ V}$, $I_C = 1.5\text{ A}$	—	200	—	ns

Application Circuit Example



External Parts

Typical external parts are shown in the following table.

Part	Typical	Purpose	Remarks
C ₁ , C ₂ , C ₃	25 V/2.2 μ F	Bootstrap capacitor	(Note 1)
C ₄	25 V/10 μ F	V _{CC} power supply stability	(Note 2)
C ₅	25 V /0.1 μ F	V _{CC} for surge absorber	(Note 2)
C ₆	25 V/1 μ F	V _{REG} power supply stability	(Note 2)
C ₇	25 V/1000 pF	V _{REG} for surge absorber	(Note 2)
R ₁	5.1 k Ω	DIAG pin pull-up resistor	(Note 3)

Note 1: The required bootstrap capacitance value varies according to the motor drive conditions. The capacitor is biased by V_{CC} and must be sufficiently derated for it.

Note 2: When using this product, adjustment is required in accordance with the use environment. When mounting, place as close to the base of this product leads as possible to improve the ripple and noise elimination.

Note 3: The DIAG pin is open drain. If the DIAG pin is not used, connect to the GND.

Handling precautions

- (1) Please control the input signal in the state to which the V_{CC} voltage is steady. Both of the order of the V_{BB} power supply and the V_{CC} power supply are not cared about either.
Note that if the power supply is switched off as described above, this product may be destroyed if the current regeneration route to the V_{BB} power supply is blocked when the V_{BB} line is disconnected by a relay or similar while the motor is still running.
- (2) The excess voltage such as the voltage surge which exceed the maximum rating is added, for example, may destroy the circuit. Accordingly, be careful of handling this product or of surge voltage in its application environment.

Description of Protection Function

(1) Under-voltage protection

This product incorporates under voltage protection circuits to prevent the IGBT from operating in unsaturated mode when the VCC voltage or the VBS voltage drops.

When the VCC power supply falls to this product internal setting VCCUVD (=11 V typ.), all IGBT outputs shut down regardless of the input. This protection function has hysteresis. When the VCC power supply reaches 0.5 V higher than the shutdown voltage (VCCUVR (=11.5 V typ.)), this product is automatically restored and the IGBT is turned on again by the input.

When the VBS supply voltage drops VBSUVD (=9 V typ.), the high-side IGBT output shuts down.

When the VBS supply voltage reaches 0.5 V higher than the shutdown voltage (VBSUVR (=9.5 V typ.)), the IGBT is turned on again by the input signal.

(2) Thermal shutdown

This product incorporates a thermal shutdown circuit to protect itself against excessive rise in temperature. When the temperature of this chip rises to the internal setting TSD due to external causes or internal heat generation all IGBT outputs shut down regardless of the input. This protection function has hysteresis ΔTSD (= 50 °C typ.). When the chip temperature falls to TSD - ΔTSD , the chip is automatically restored and the IGBT is turned on again by the input.

Because the chip contains just one temperature-detection location, when the chip heats up due to the IGBT, for example, the differences in distance between the detection location and the IGBT (the source of the heat) can cause differences in the time taken for shutdown to occur. Therefore, the temperature of the chip may rise higher than the initial thermal shutdown temperature.

Safe Operating Area

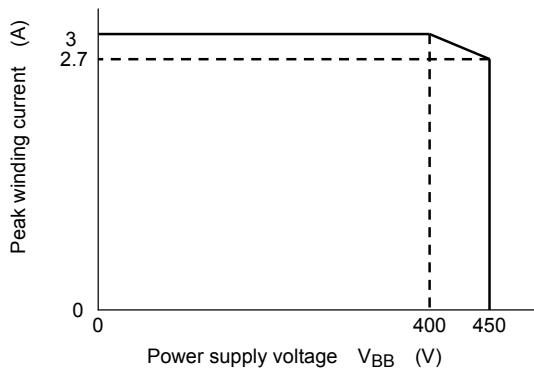
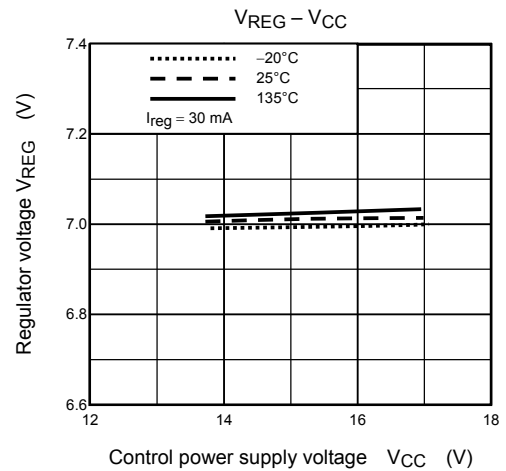
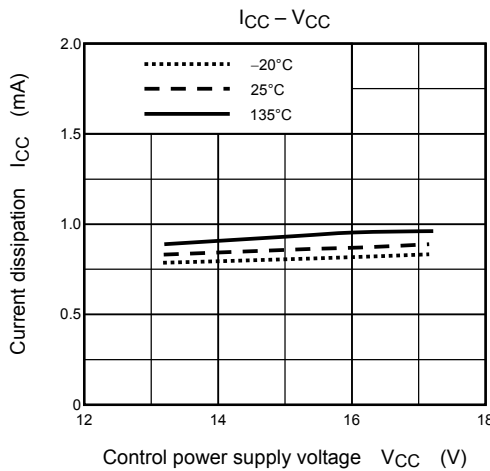
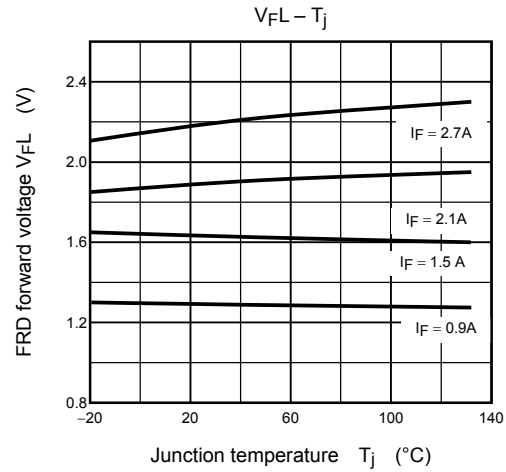
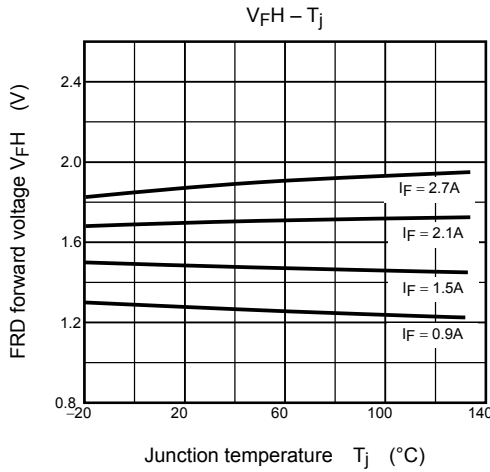
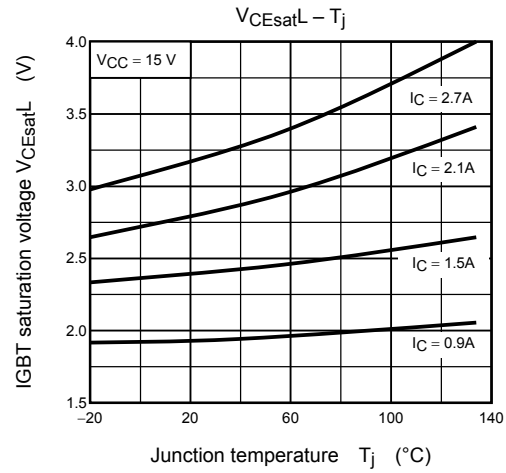
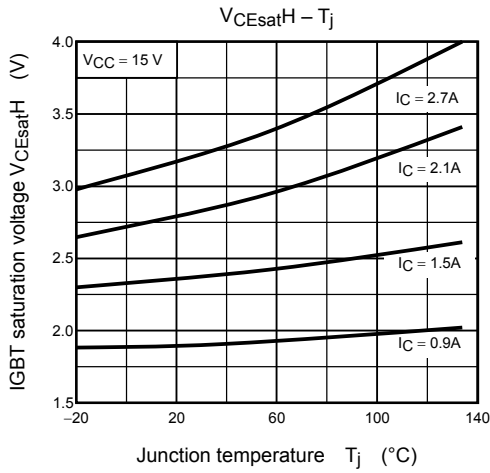
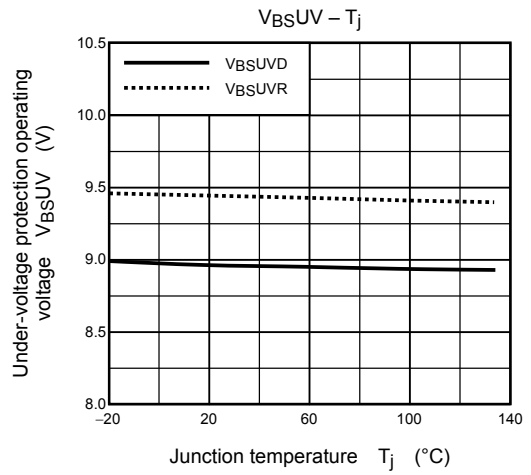
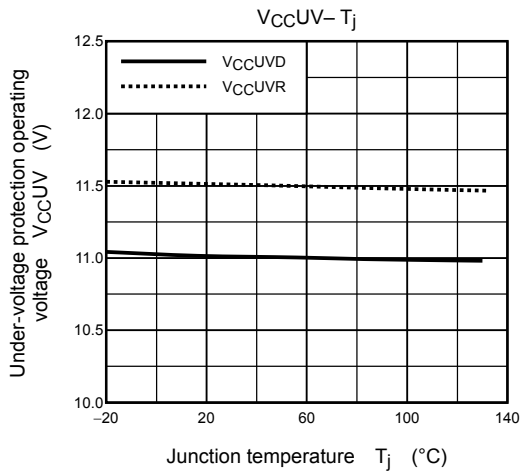
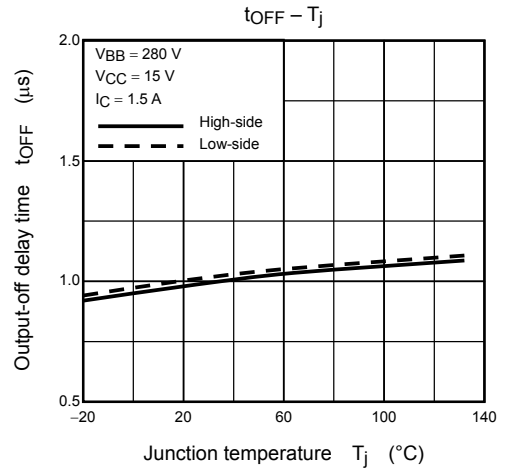
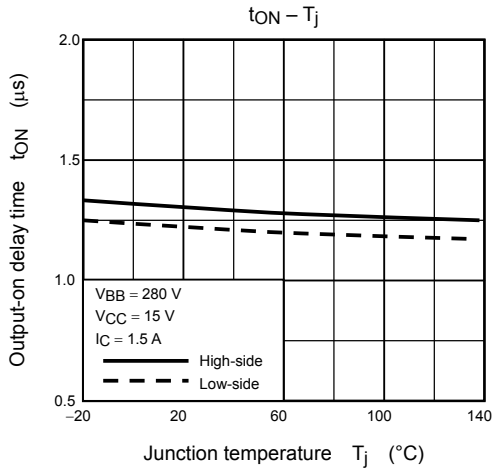
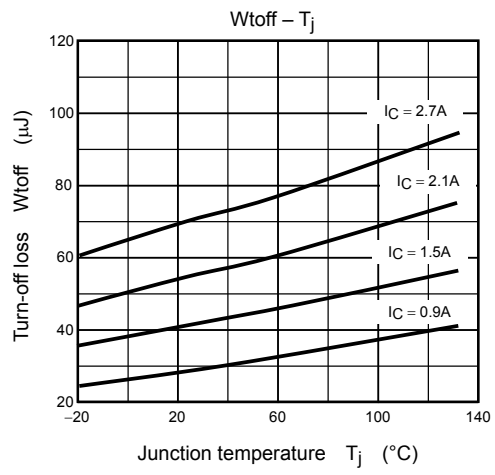
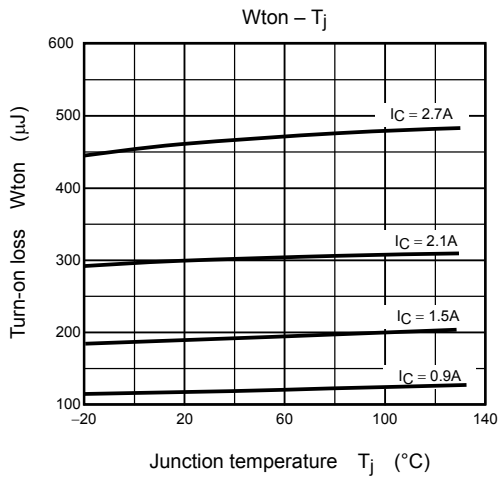
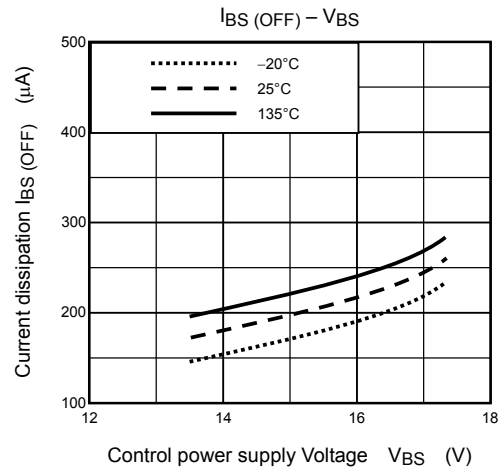
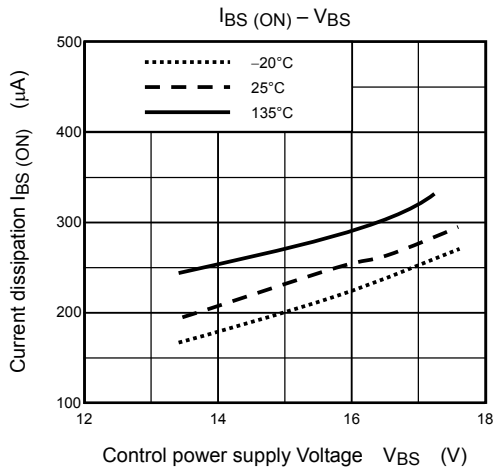


Figure 1 SOA at $T_j = 135^\circ\text{C}$

Note 1: The above safe operating areas are at $T_j = 135^\circ\text{C}$ (Figure 1).

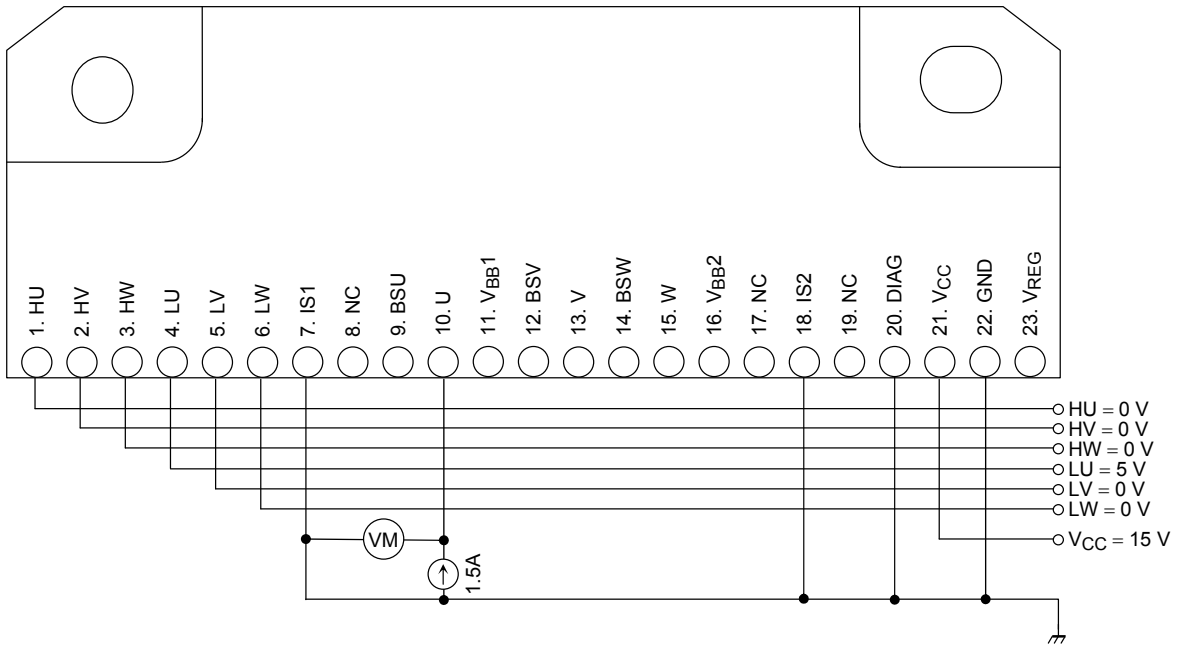




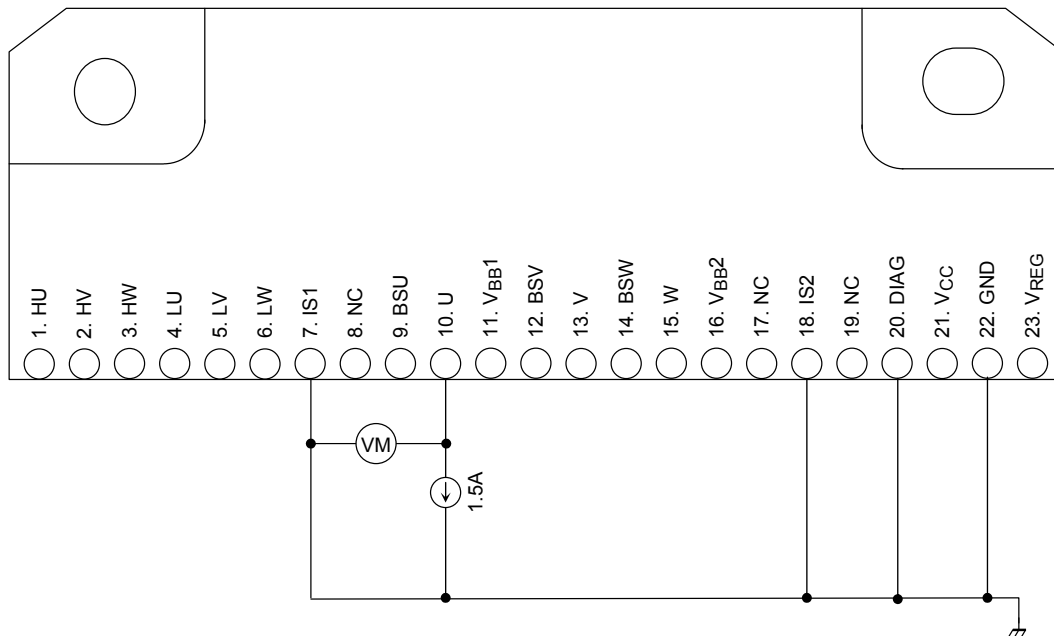


Test Circuits

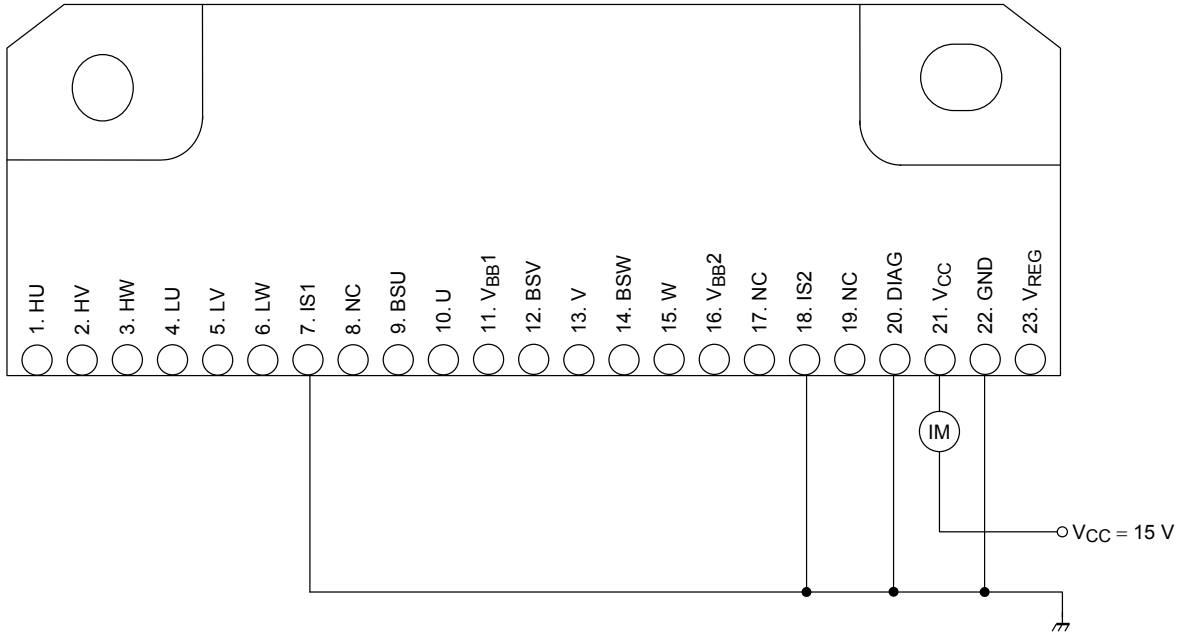
IGBT Saturation Voltage (U-phase low side)



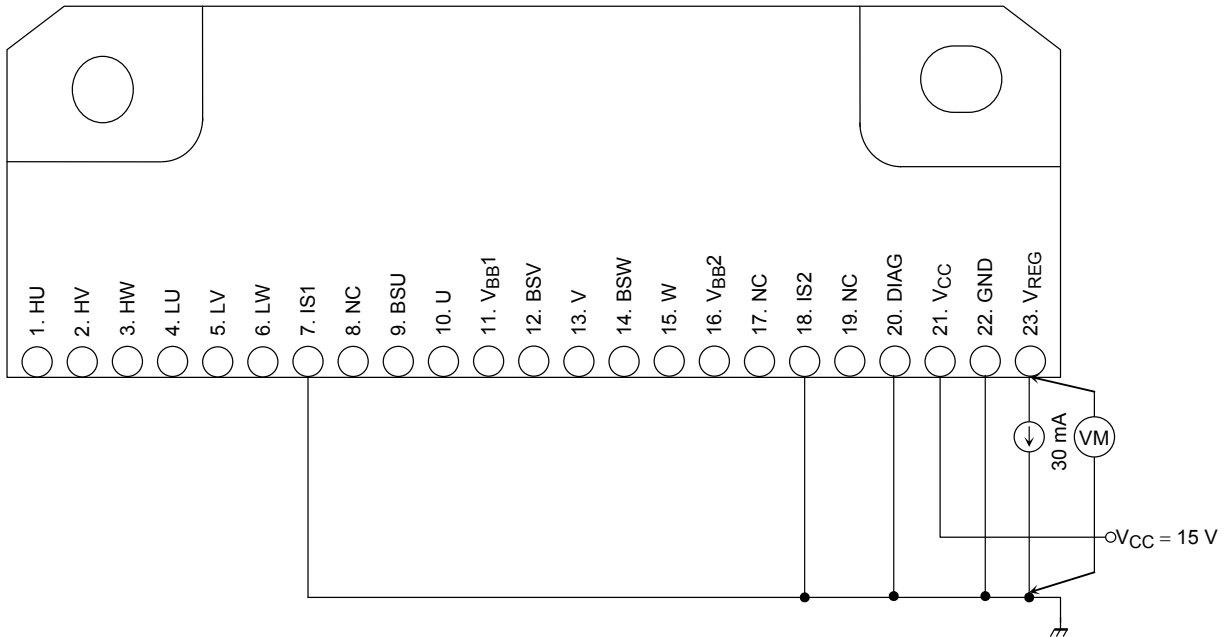
FRD Forward Voltage (U-phase low side)



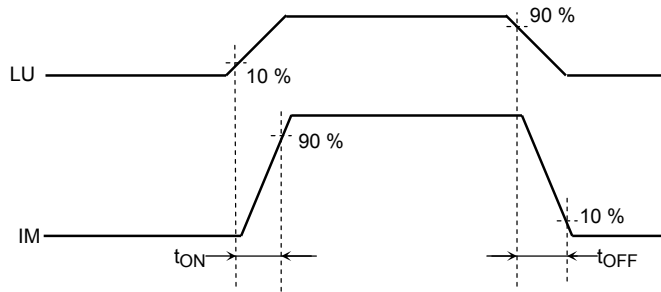
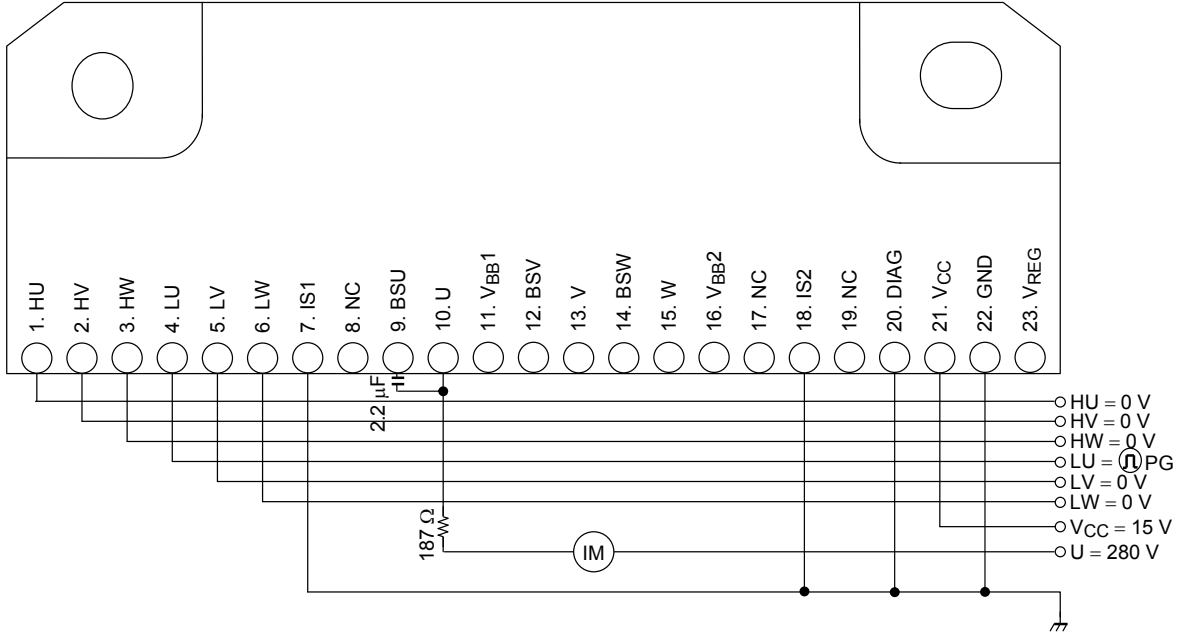
V_{CC} Current Dissipation



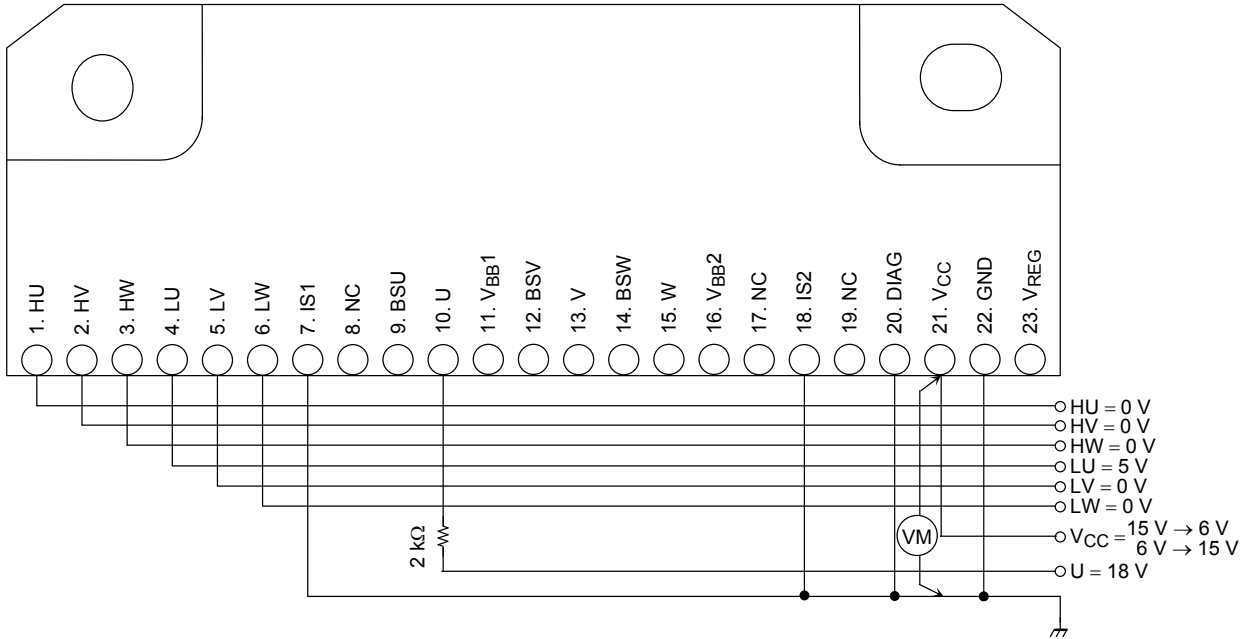
Regulator Voltage



Output ON/OFF Delay Time (U-phase low side)



V_{CC} Under-voltage Protection Operating/Recovery Voltage (U-phase low side)

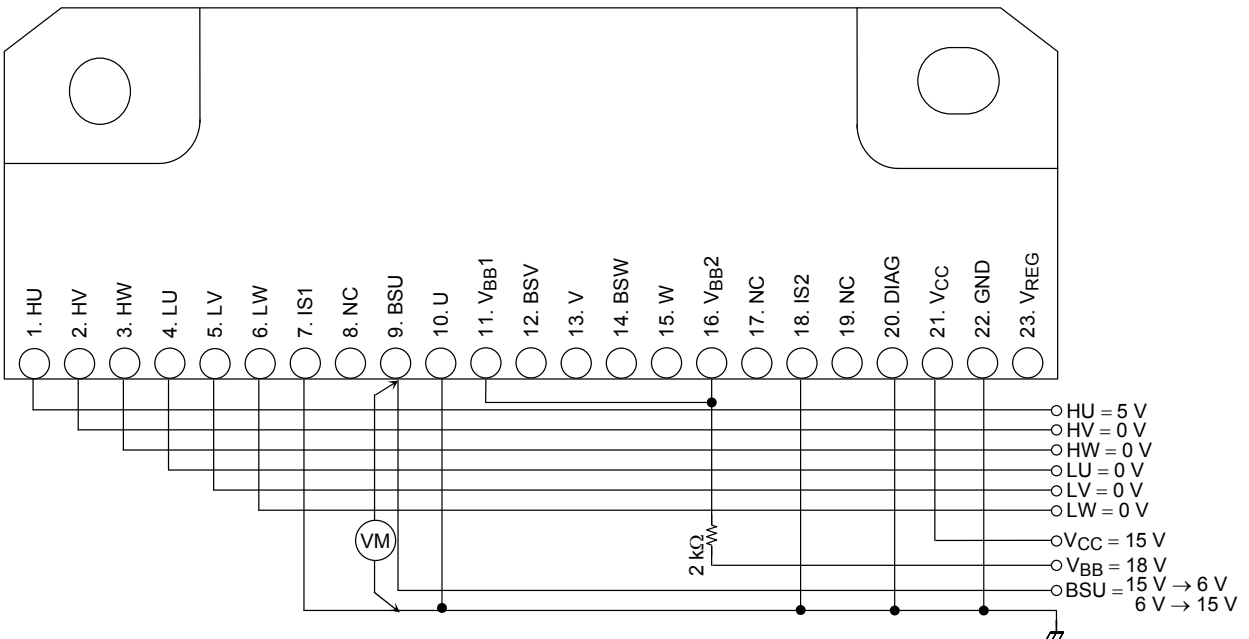


*:Note:Sweeps the V_{CC} pin voltage from 15 V to decrease and monitors the U pin voltage.

The V_{CC} pin voltage when output is off defines the under voltage protection operating voltage.

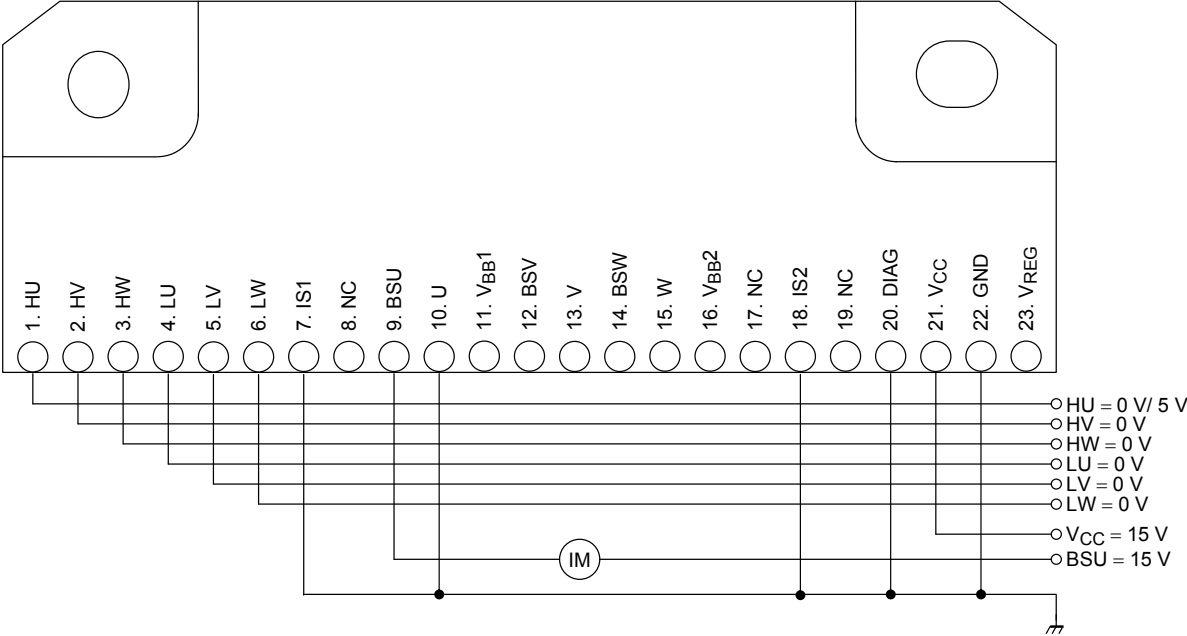
Also sweeps from 6 V to increase. The V_{CC} pin voltage when output is on defines the under voltage protection recovery voltage.

V_{BS} Under voltage Protection Operating/Recovery Voltage (U-phase high side)

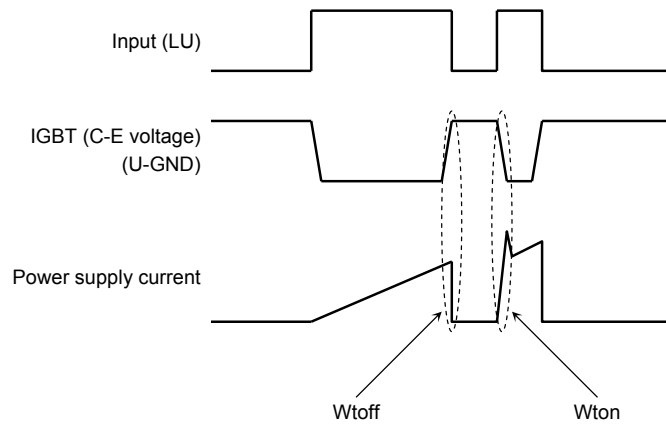
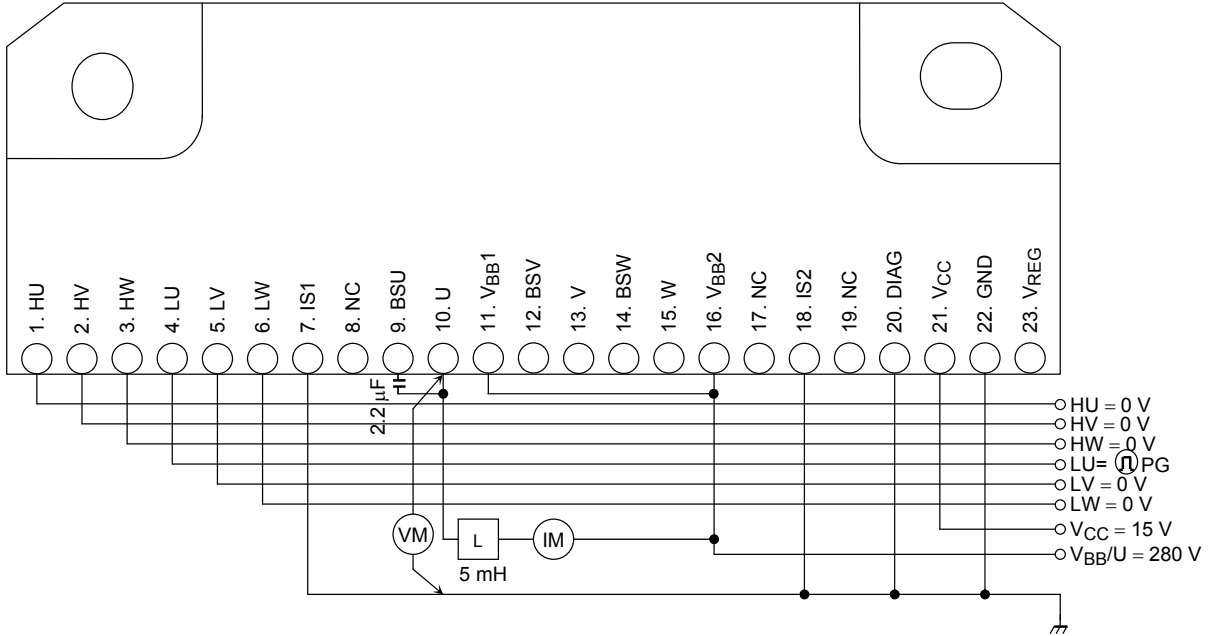


*:Note:Sweeps the BSU pin voltage from 15 V to decrease and monitors the V_{BB} pin voltage. The BSU pin voltage when output is off defines the under voltage protection operating voltage. Also sweeps the BSU pin voltage from 6 V to increase and change the HU pin voltage at 5 V → 0 V → 5 V each time. It repeats similarly output is on. When the BSU pin voltage when output is on defines the under voltage protection recovery voltage.

V_{BS} Current Dissipation (U-phase high side)



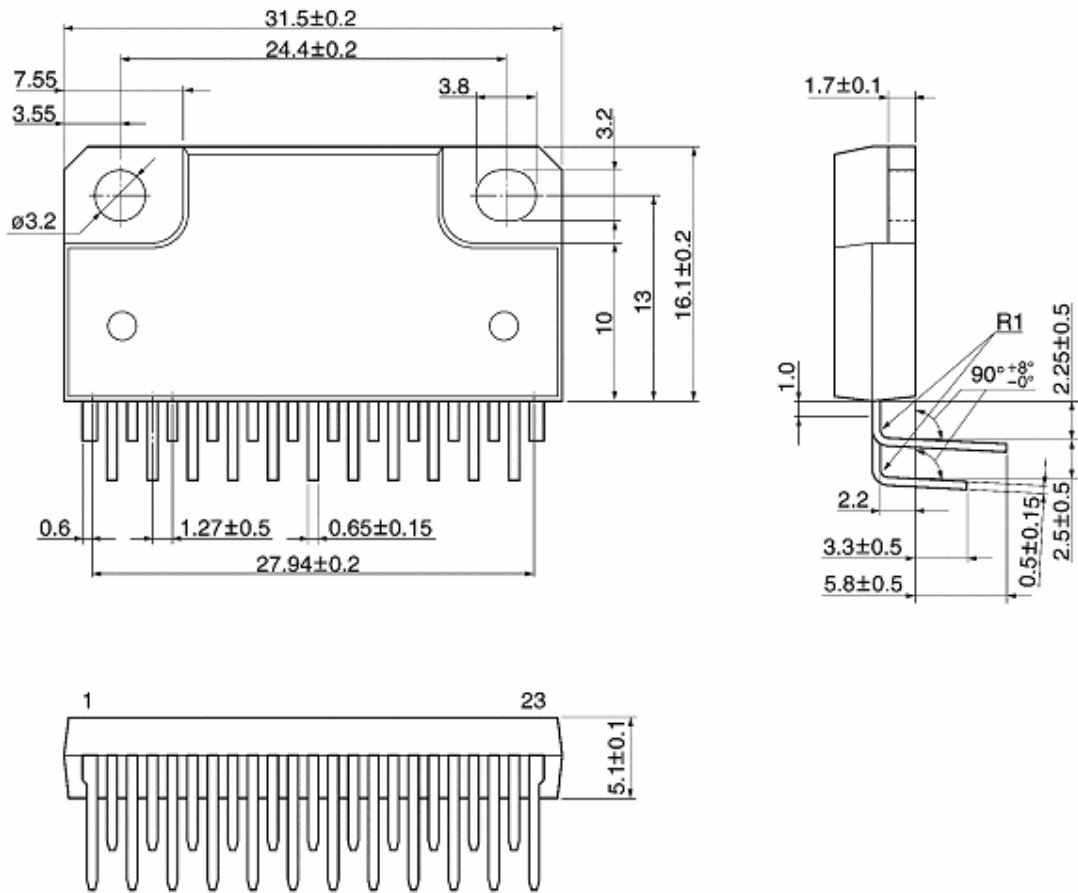
Turn-On/Off Loss (low side IGBT + high side FRD)



Package Dimensions

HZIP23-P-1.27F

Unit: mm

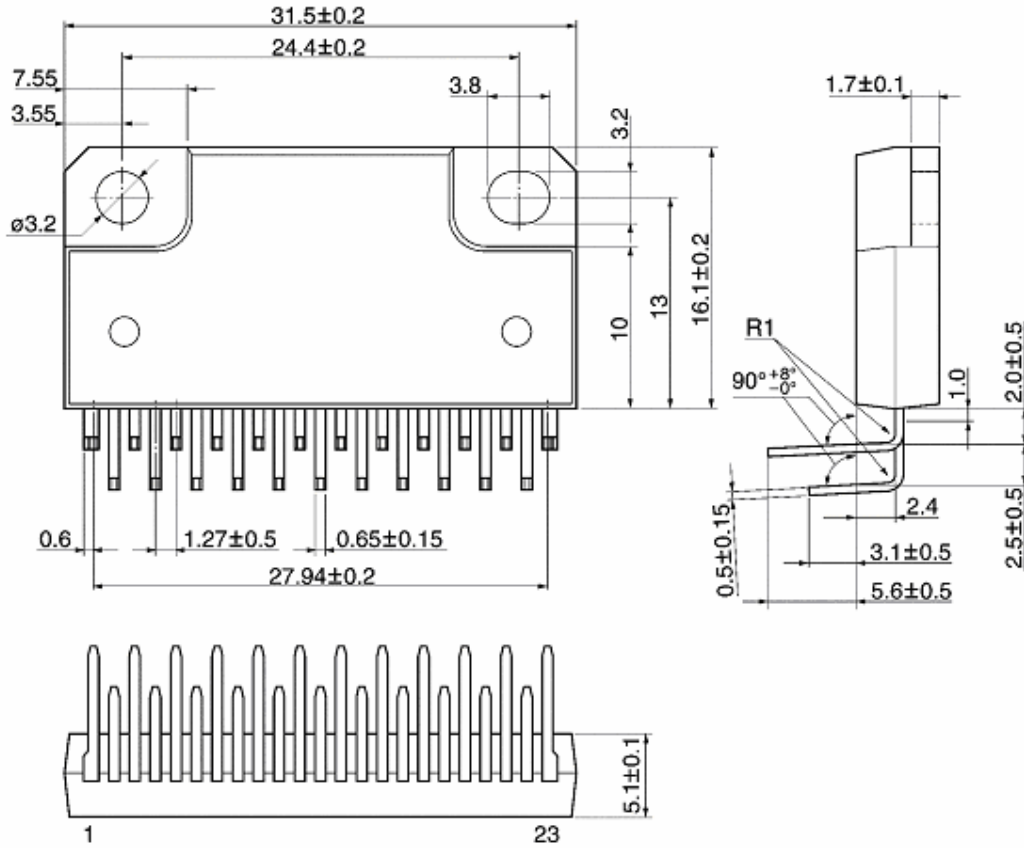


Weight: 6.1 g (typ.)

Package Dimensions

HZIP23-P-1.27G

Unit: mm

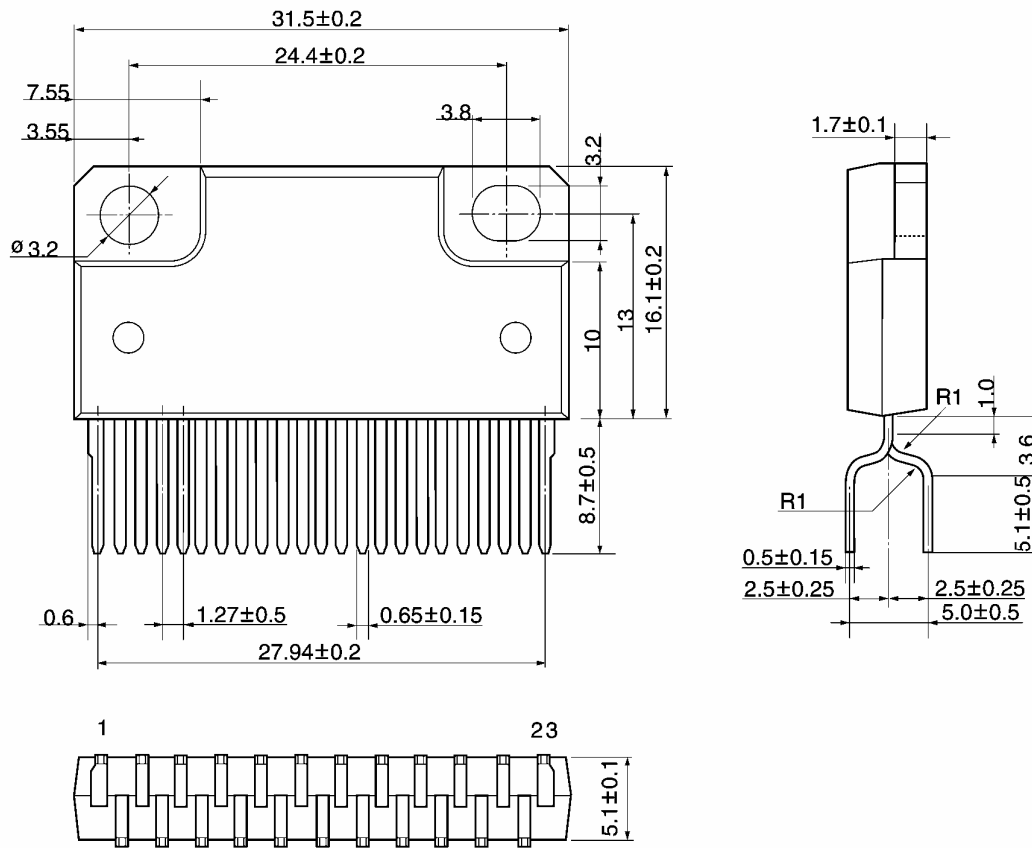


Weight: 6.1 g (typ.)

Package Dimensions

HZIP23-P-1.27H

Unit: mm



Weight: 6.1 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN

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